# MicomRM1200

Power Amplifer



With it's strict precision design, the fully solid-state amplifier features the latest and most advanced technology, providing exceptional linearity, efficiency and operating dependability for HF radio voice and data communications.





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# **Power Amplifer**

# Maximum Durability and Communication Reliability

- Conservatively rated circuits deliver full power, hour after hour, for voice, CW and data (RTTY, ARQ, PACKET) service
- The amplifier circuitry is designed for the rapid switching inherent in ARQ operation. Reliability of ARQ systems is further improved by the stronger signal from a 1 KW amplifier
- 100% solid state, modular design MOS-FET power transistors in interchangeable and field replaceable 300 modules consumes less power than tube amplifiers and allows for easy servicing
- Antenna mismatch protection prevents amplifier damage and spurious energy in case of an extreme antenna mismatch
- With Failsoft operation, dual power supplies and parallel amplifier modules maintain operation at reduced power even in the unlikely event of total failure, allowing uninterrupted communications
- Built-in protective circuitry ensure amplifier is not damaged during abnormal conditions

## **Options**

- Rack 19"
- 18 DBB1 for interface with other radios

### **User-friendliness**

- Full compatibility with all Micom radios allows maximum flexibility in systems designs. Amplifier can also operate with an existing system
- Broadband design provides fully automatic tuning and adjustments
- · Current and Power meters allow for easy monitoring.
- Remote control panel offers convenient amplifier operating and control
- Controller board incorporating a 16-bit micro processor centralizes all sensory status information and controls the amplifier's band selection, autotuner operation, maintenance and protective functions
- Built-in-Test Equipment for exceptional amplifier dependability

## Bite RS232 Interface Protection

- Amplifier module current imbalance
- Out-of-band frequency input
- Short and Open RF output
- Input overdrive
- Over-current
- Under voltage%
- · High temperature
- High VSWR

### Electrical

Power output 1200 W PEP

1000 W average

(±0.5 dB) into 1.5:1 VSWR 4:1 VSWR - min 50% power

Frequency range 1.6-30 MHz

Power input 20 Watts nominal

(0 dBm option)

Harmonic emission -60 dBc

Frequency switching Tuning process (100 msecO max

between switching channels)

Input impedance: 50 Ohm

T/R switching: 10 msec maximum R/T switching 10 msec maximum

Rx bypass mode Rx/Tx switch, active at receive

### **Environmental**

Temperature  $-10^{\circ}\text{C to } +60^{\circ}\text{C}$ Humidity  $95\% @ 50^{\circ}\text{C}$ Input RF N type connector Output RF N type connector

Control/Monitor D type 25 pins connector

(including PTT, BIT, VSWR, Incident power, Tune mode, on/off)

#### **Features**

19 inch rack mountable

Supply AC voltage 90-264 VAC, 47-63% (single phase)

Redundancy power supply (2 modules)
2 Amplifiers 600 each
125 Watt from the micom

Automatic bypass backup Manual bypass selection

Automatic step-down power levels

# Specifications

Model FLN3175

to be used with transceivers micomRM125, model:

M91AMN0KV5-K & G638 micomRM125R, model: M95AMN0KV5-K & G638



COMSYSTEMS Solutions. Tel +1 (239) 293-9991 Fax +1 (239) 236-0886 Email: sales@comsystems.com